

VTTL060R50BNA

Datasheet





VTTL060R50BNA

General Description

V _{(BR)DSS}	R _{DS(ON)_max}	I_D
600V	5.0Ω@10V	2A

Symbol

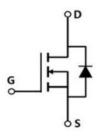


Figure 1 Symbol of VTTL060R50BNA

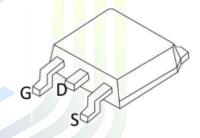
Features

- \blacksquare Low $R_{DS(on)}$
- Low FOM
- Extremely low switching loss
- Good stability and uniformity

Application

- Consumer electronics power supply
- LED Lighting
- Standby Power
- Charger

Package Type



TO-252-2L

Figure 2 Package Type of VTTL060R50BNA

Ordering Information





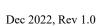
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Absolute Maximum Ratings (T_A= 25 °C, unless otherwise specified)

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	V _{DSS}	600	V
Gate-Source Voltage	V _{GSS}	±30	V
Continuous Drain Current ^{Note1} T _A = 25 °C	I_D	2	
Pulsed Drain Current Note2	I_{DM}	9	A
Avalanche Current ^{Note3}	I _{AS}	5.9	
Single Pulsed Avalanche Energy ^{Note3}	Eas	8.7	mJ
Total Power Dissipation ^{Note5} $T_C=25$ °C	P _D	56.8	W
Junction Temperature	TJ	150	°C
Storage Temperature	Tstg	-55 to 150	°C

Thermal Resistance

Parameter	Symbol	M in	T <mark>y</mark> p	Max	Unit
Thermal Resistance, Junction-to-Case ^{Note6}	$R_{ heta m JC}$		2.1		°C/W





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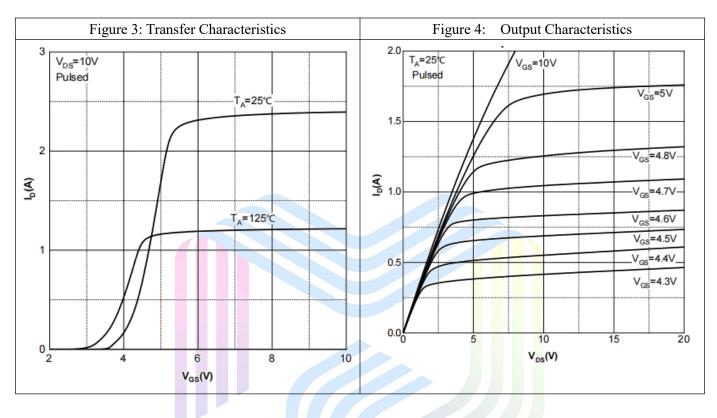
Electrical Characteristics (T_J= 25 °C, unless otherwise specified)

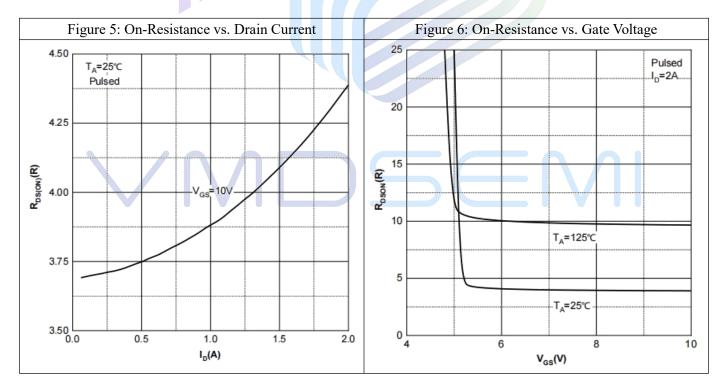
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Statistic Characteristics						
Drain-Source Breakdown Voltage	$\mathrm{BV}_{\mathrm{DSS}}$	$V_{GS}=0V, I_{D}=250uA$	600			V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = 600V, V_{GS} = 0V$			1	uA
Gate-Body Leakage Current	I_{GSS}	$V_{GS} = \pm 30V, V_{DS} = 0V$			±100	nA
Gate Threshold Voltage ^{Note4}	$V_{\text{GS(th)}}$	$V_{DS}=V_{GS}$, $I_D=250uA$	2.0	3.2	4.0	V
Static Drain-Source On-Resistance ^{Note4}	$R_{DS(\mathrm{ON})}$	$V_{GS}=10V, I_D=1A$		3.9	5.0	Ω
Dynamic Characteristics						
Input Capacitance	C _{ISS}	V _{DS} =50V		339		pF
Output Capacitance	Coss	$V_{GS}=0V$		25.3		pF
Reverse Transfer Capacitance	C_{RSS}	f=1MHz		2.2		pF
Total Gate Charge	Q_{g}	V _{DS} =300V		3.2		
Gate-Source Charge	Q_{gs}	$V_{GS}=10V$		1.2		nC
Gate-Drain Charge	Q_{gd}	$I_D=1A$		1.4		
Gate Resistance	Rg	f = 1MHz, Open drain		3.3		Ω
Switching Parameters						
Turn-on Delay Time	$t_{d(on)}$	$V_{DD}=300V$		12		
Turn-on Rise Time	$t_{\rm r}$	$V_{GS}=10V$		21		***
Turn-off Delay Time	$t_{ m d(off)}$	$I_D=2A$		30		ns
Turn-off Fall Time	t_{f}	$R_G=3\Omega$		24		
Diode Characteristics						
Diode Forward Voltage Note4	$ m V_{SD}$	$V_{GS}=0V$, $I_S=2A$			1.2	V

Notes:

- 1. The maximum current rating is limited by package. And device mounted on a large heatsink.
- 2. Pulse Test : Pulse Width $\leq 10\mu s$, duty cycle $\leq 1\%$.
- $3.E_{AS}$ condition: $V_{DD} = 100V$, $V_{GS} = 10V$, L = 0.5 mH, $R_G = 25 \Omega$ Starting $T_J = 25 ^{\circ}\text{C}$.
- 4. Pulse Test : Pulse Width $\leq 300 \mu s$, duty cycle $\leq 2\%$.
- 5. The power dissipation P_D is limited by $T_{J(MAX)} = 150$ °C. And device mounted on a large heatsink
- 6.Device mounted on 1in² FR-4 board with 2oz. Copper, in a still air environment with T_A =25°C.

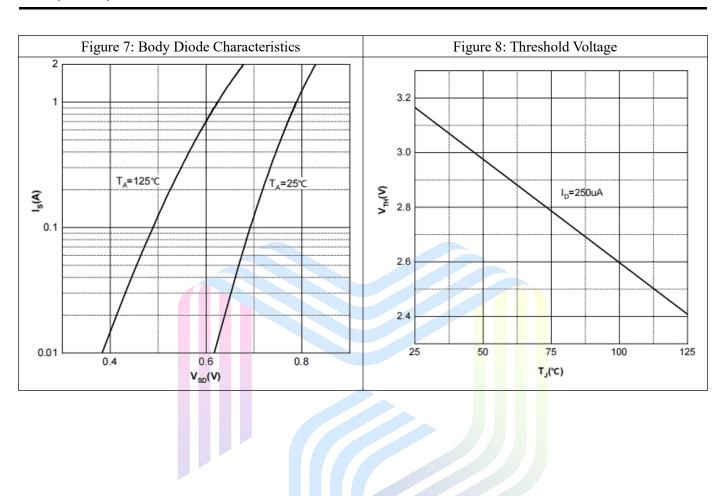
Typical Performance Characteristics







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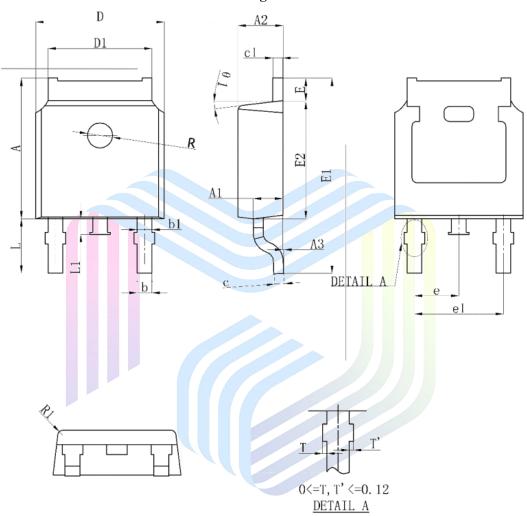






Mechanical Dimensions:

TO-252-2L Package Information



Cumbal	Dimensions	n Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
Α	7.050	7.150	0.278	0.281	
A1	0.960	1.060	0.038	0.042	
A2	2.200	2.400	0.087	0.094	
A3	0.000	0.100	0.000	0.004	
b	0.760	0.760REF		REF	
b1	1.000	REF	F 0.039REF		
С	0.508	BREF	0.020REF		
c1	0.508	BREF	0.020REF		
D	6.550	6.650	0.258	0.262	
D1	5.100	5.460	0.201	0.215	
E	0.950	1.050	0.037	0.041	
E1	9.700	10.400	0.382	0.409	
E2	6.000	6.200	0.236	0.244	
е	2.286	BSC	0.090BSC		
e1	4.572REF		0.180REF		
L	2.650	2.950	0.104	0.116	
L1	0.700	0.900	0.028	0.035	
θ1	7°F	REF	7°F	REF	
R	1.300	OREF	0.051REF		
R1	0.250	REF	0.010REF		



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